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Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

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By: I fine Cam Can

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hong Koo Kim

Application No.: 09/747,779

Filed: December 22, 2000

For: FABRICATION METHOD AND STRUCTURE FOR FERROELECTRIC NONVOLATILE MEMORY FIELD

**EFFECT TRANSISTOR** 

Examiner:

Marcos D. Pizarro Crespo

Technology Center/Art Unit: 2814

PRELIMINARY AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Prior to examination of the above-referenced application, please enter the following amendments and remarks:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.

07/29/2003 HBERHE

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